Session-conference of the Nuclear Physics Section of the PSS RAS, dedicated to the 70th anniversary of V.A. Rubakov

NEW TECHNIQUE OF ION IDENTIFICATION IN ACCELERATOR MASS SPECTROMETRY USING LOW-PRESSURE TPC WITH GEM READOUT

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- 1. Accelerator mass spectrometry
- 2. New concept of ion identification. Proof of Concept.
- 3. Experimental setup
- 4. Measurements of energy spectra and track ranges
- 5. Recent results with AMS

Isotopes used for dating

Analyzed isotopes	Half life	Stable isotopes	Stable isobars
¹⁰ Be	1,39 million years	⁹ Be	¹⁰ B
¹⁴ C	<mark>5730 years</mark>	^{12,13} C	¹⁴ N [*]
²⁶ Al	717 thousand years	²⁷ Al	²⁶ Mg*
³⁶ Cl	301 thousand years	^{35,37} Cl	³⁶ Ar [*] , ³⁶ S
⁴¹ Ca	102 thousand years	^{40,42,43,44} Ca	⁴¹ K
¹²⁹	15,7 million years	127	¹²⁹ Xe*

* - isobars that do not form stable negative ions.

In the current AMS BINP setup the time-of-flight technique is used for the carbon isotopes separation. But that technique has a serious problem of separating the isobars - different chemical elements having the same atomic mass. The typical example are radioactive isotopes ¹⁰Be and ¹⁰B.

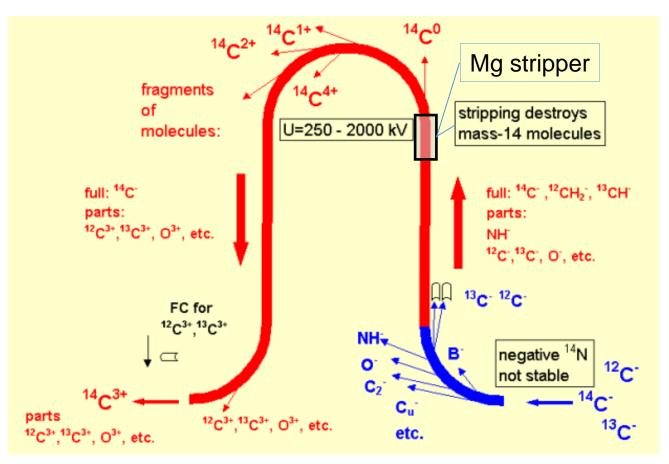
Accelerator mass spectrometry



Accelerator mass spectrometry (AMS) is an ultrasensitive method of counting individual atoms. Usually it is the rare radioactive atoms with a long half-life. The archetypal example is ¹⁴C which has a half-life of 5730 years and an abundance in living organisms of 10⁻¹² relative to stable ¹²C isotope.

AMS facilities operate in more than 100 physical laboratories worldwide, two of them are located in Novosibirsk at Geochronology of the Cenozoic Era Center for Collective Use and Novosibirsk State University.

BINP AMS



BINP AMS provides reliable separation of a pure beam of radiocarbon ions from the accompanying ion background.

1. Formation of an ion beam from atoms of the test sample

- 2. Ion selection at low energy
- 3. Ion acceleration

4. Recharging of atomic ions and destruction of molecular ions in magnesium target

5. Ion selection in a high voltage terminal

6. Ion acceleration

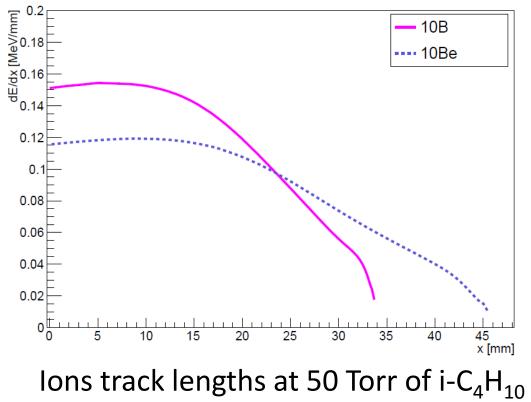
7. Ion selection at high energy

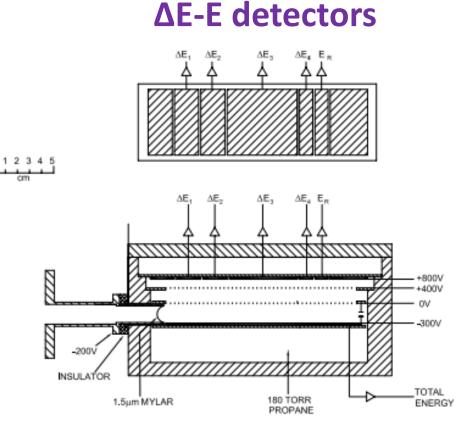
8. Identification and counting of ions

Traditional concept of ion identification at AMS

Detectors used to count the AMS isotope:

- silicon detectors;
- time-of-flight systems (*BINP AMS*);
- ionization chambers.



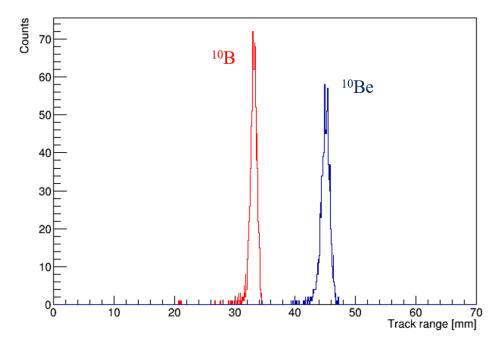


A cross section through the multi-element ionization chamber. The upper panel shows a plan view of the anode electrode.

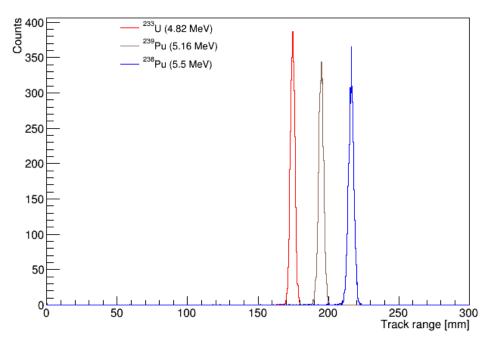
Proof of concept: measuring track ranges

SRIM (The Stopping and Range of Ions in Matter Software) –

is a collection of software packages which calculate many features of the transport of ions in matter.



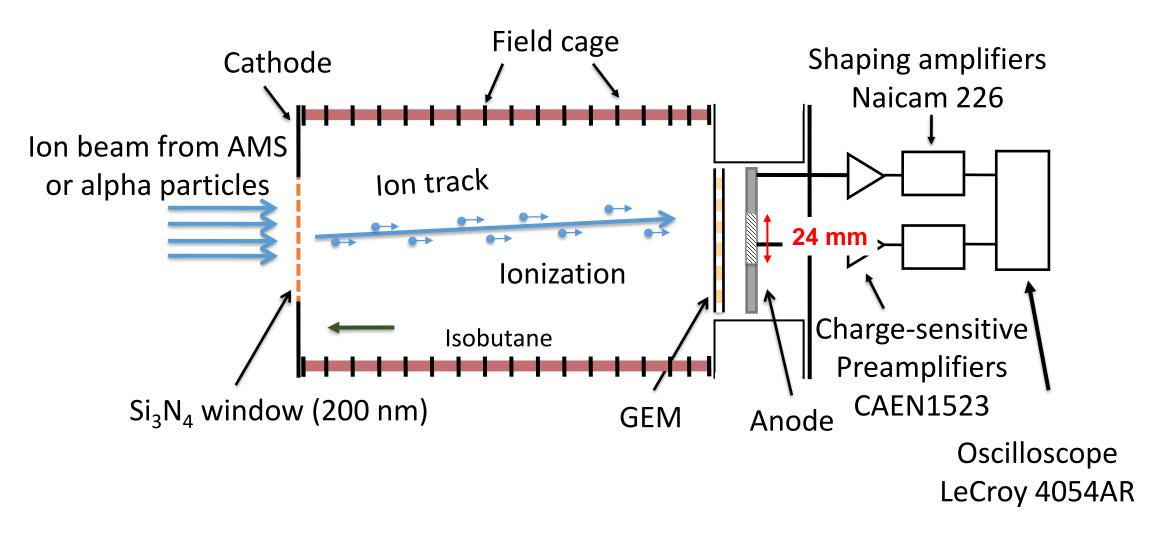
Track ranges distributions in the low-pressure TPC for 4.025MeV ¹⁰B and ¹⁰Be ions for 200 nm silicon nitride window and 50 torr isobutane, obtained using SRIM simulation.



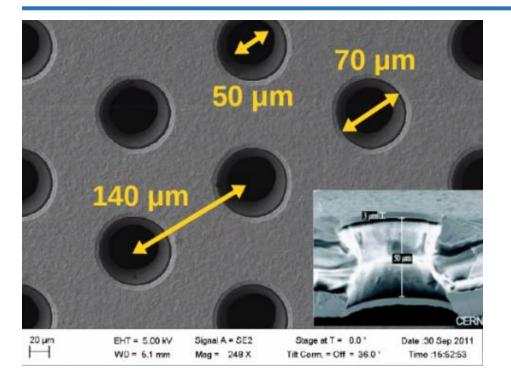
Ion ranges distributions in the low-pressure TPC for alpha particles with different energies for 200 nm silicon nitride window and 50 torr isobutane, obtained using SRIM simulation.

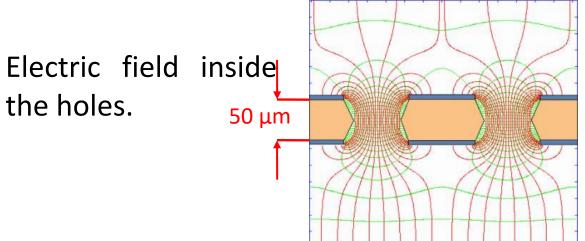
New concept of ion identification: low-pressure TPC

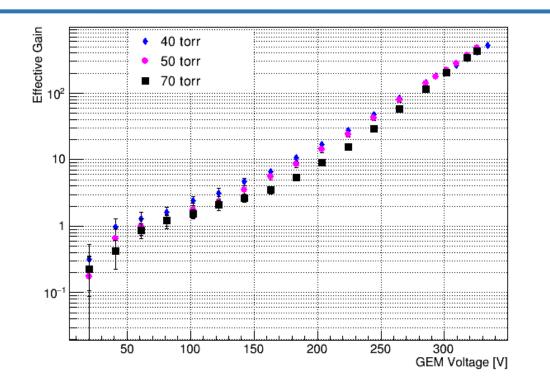
Schematic layout



Effective gain of GEM

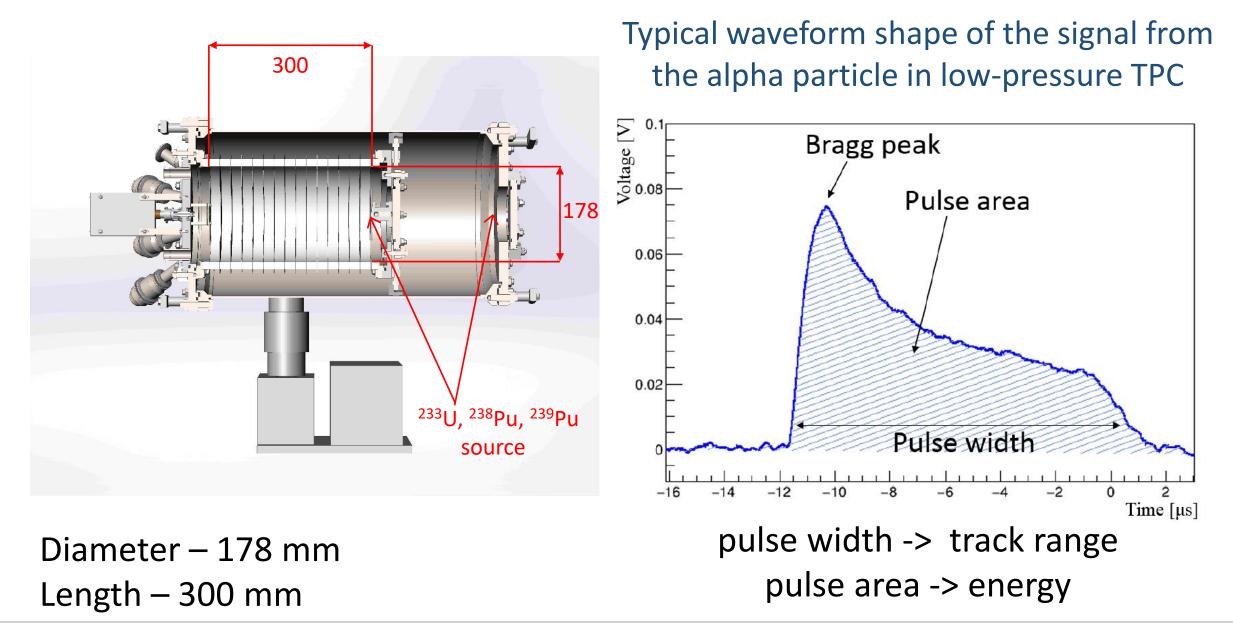






GEM effective gain as a function of the voltage in isobutane at pressures varying from 40 to 70 torr in the low-pressure TPC.

TPC Prototype: Principle of operation

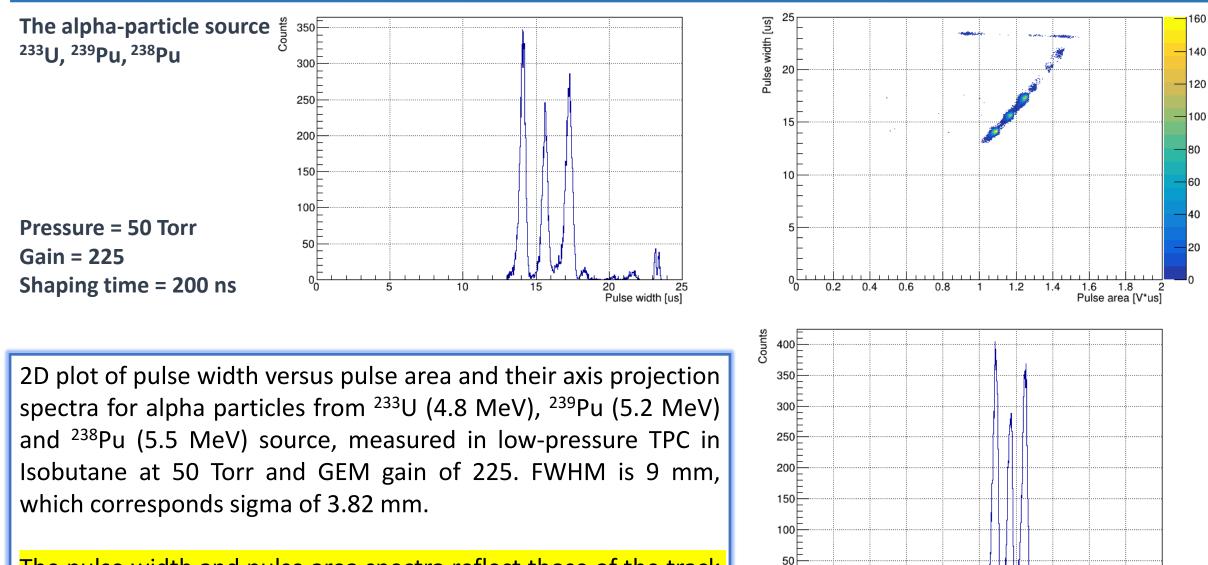


Test installation



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The measurement of track ranges



The pulse width and pulse area spectra reflect those of the track range and energy.

1.8

Pulse area [V*us]

0.8

1

1.2

1.4

1.6

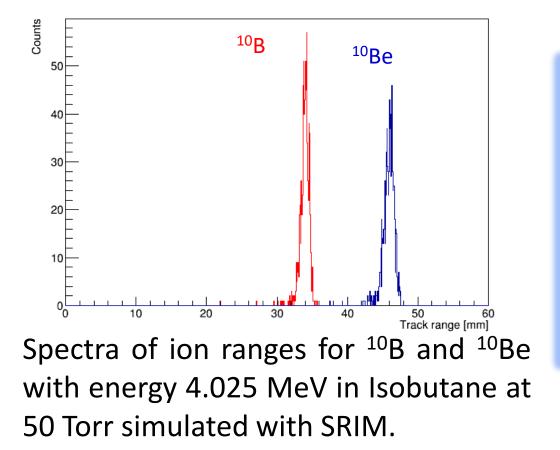
0.6

0.2

0.4

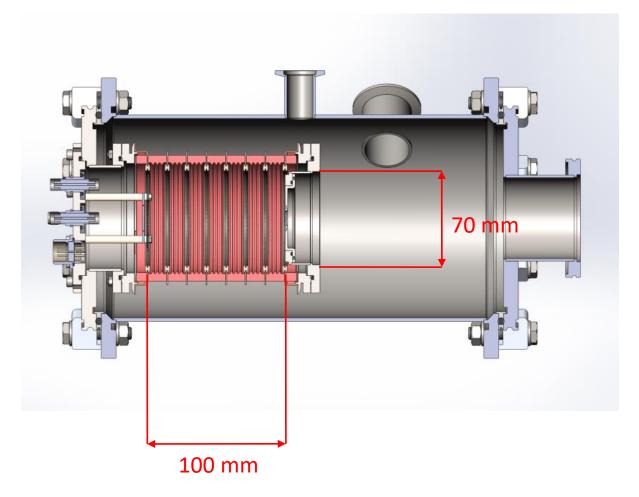
Results

Source	9	Shaping time	Gain	Pressure	Sigma/Range, %	Separation in sigma between two peaks
3 isotop	es	200 ns	225	50 Torr	12.04	3.13



Using these results and SRIM code simulations, it is shown that isobaric boron and beryllium ions can be effectively separated at AMS, providing efficient dating at a 10 million years scale. This technique will be applied in the AMS facility in Novosibirsk.

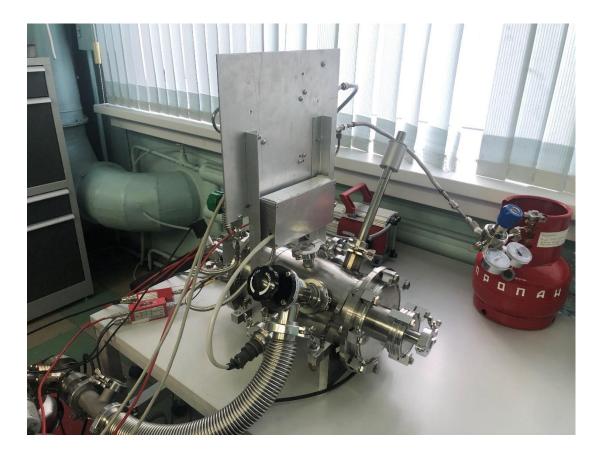
TPC for BINP AMS





TPC for BINP AMS





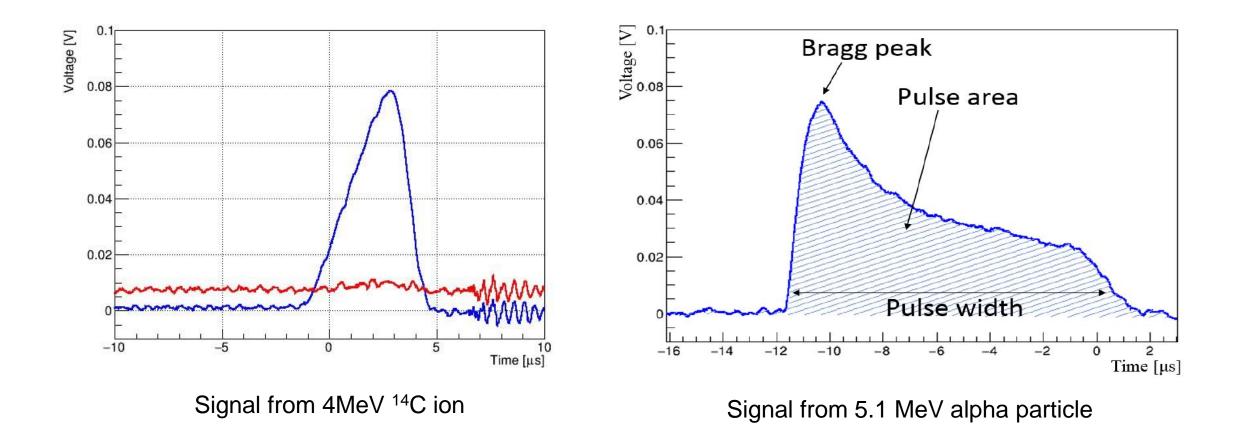
Test of the low-pressure TPC in laboratory, before installation.

Installation of TPC on BINP AMS

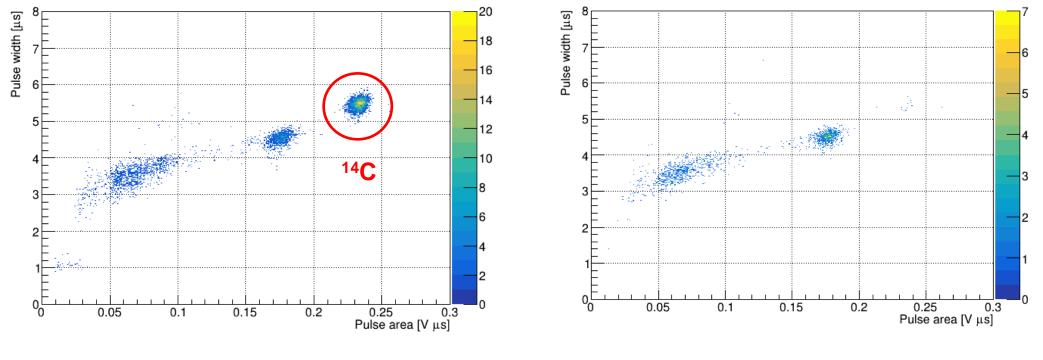


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Signal from ¹⁴C and ⁴He



Results on carbon beam



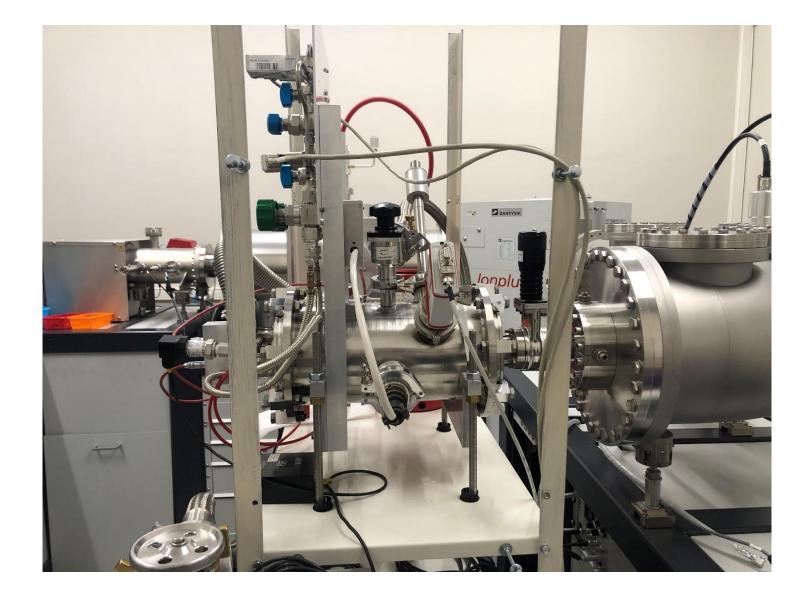
Sample with "dead" carbon sample

Sample with "alive" carbon sample

- A new concept of the detector for the accelerator-based mass spectrometer was proposed for identifying ions by their stopping range in gas;
- A low-pressure TPC prototype, based on this concept, have been made and successfully tested;
- The TPC have been installed on AMS;
- First results on ¹⁴C beam are promising;
- We are preparing to the tests with ¹⁰Be samples.

Thank you for your attention!

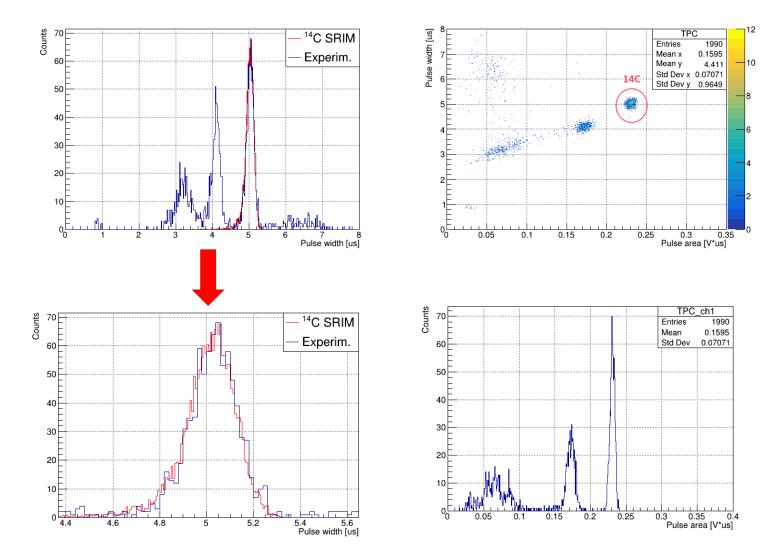
Installation of TPC on MICADAS



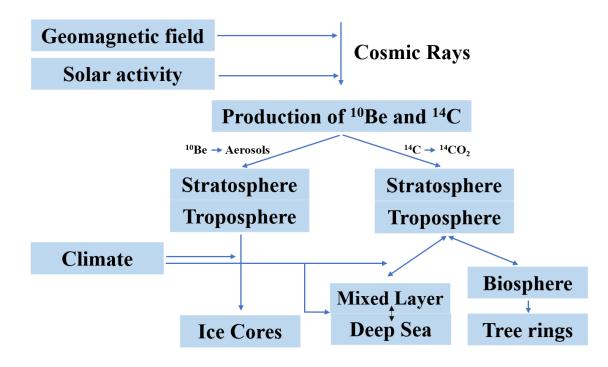
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Backup slides

Results on carbon beam



Formation and application ¹⁰Be



Time intervals of dating:

¹⁴C from 300 years to 40-60 thousand years
¹⁰Be from 1 thousand years to 10 million years

Application in-situ and meteoric ¹⁰Be:

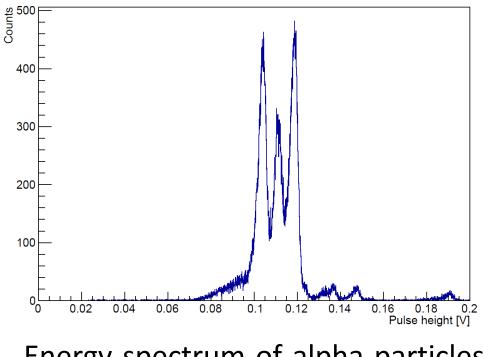
- exposure dating to identified the growths and decays of the Antarctic ice sheet;
- > understanding ice shelf collapse history;
- paleomagnetic excursions history reconstructions using ice cores;
- Inderstanding the erosion rates using depth profiles of mid latitudes outcrops;
- identifying the timing of formation of the impact crater and so forth.

Measurements of energy spectra using semiconductor detector

Alpha particle source–²³³U, ²³⁹Pu , ²³⁸Pu

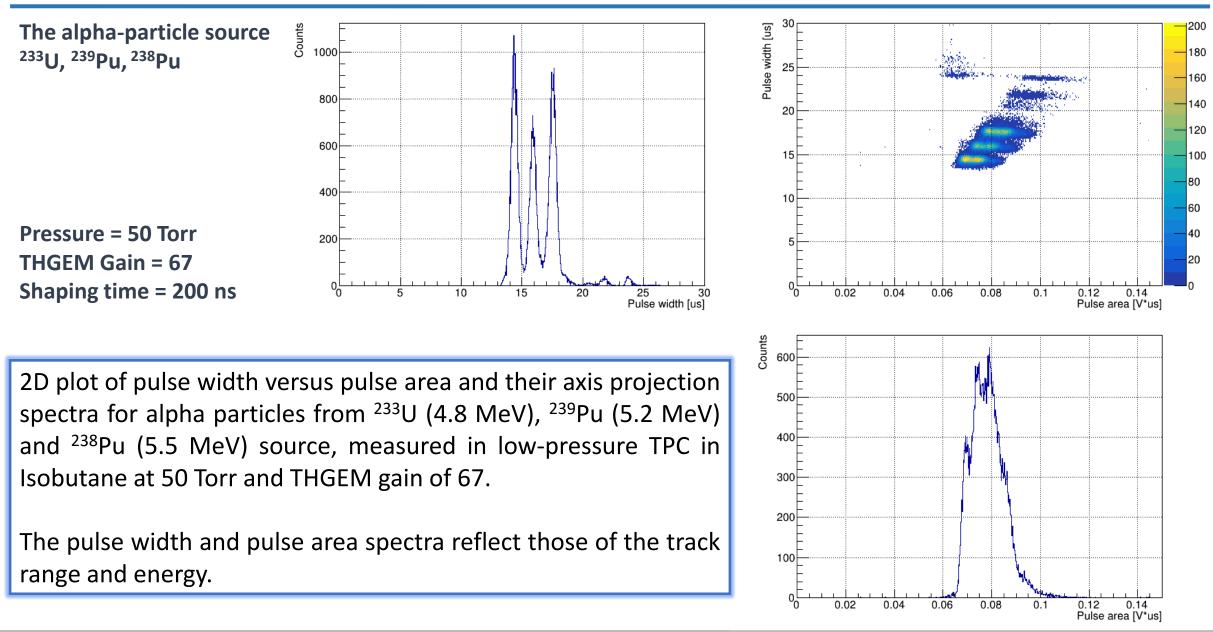


Si Charged Particle Radiation Detectors for Alpha Spectroscopy



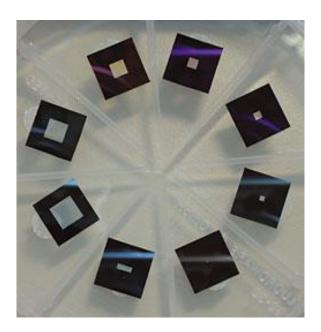
Energy spectrum of alpha particles from ²³³U (4.8 MeV), ²³⁹Pu (5.2 MeV) and ²³⁸Pu (5.5MeV) sources, measured using semiconductor detector

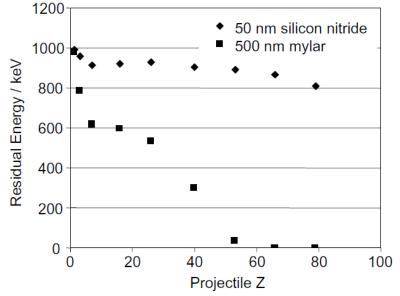
The measurement of track ranges

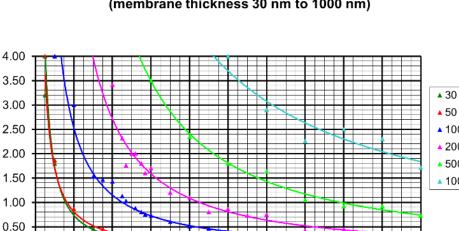


Silicon nitride membrane windows

Silson







Maximum differential pressure v membrane size (membrane thickness 30 nm to 1000 nm)

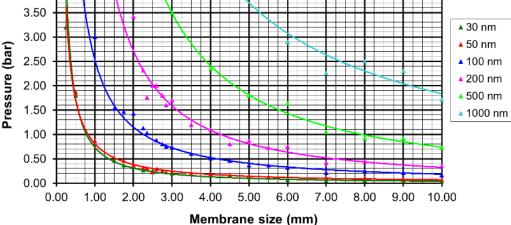
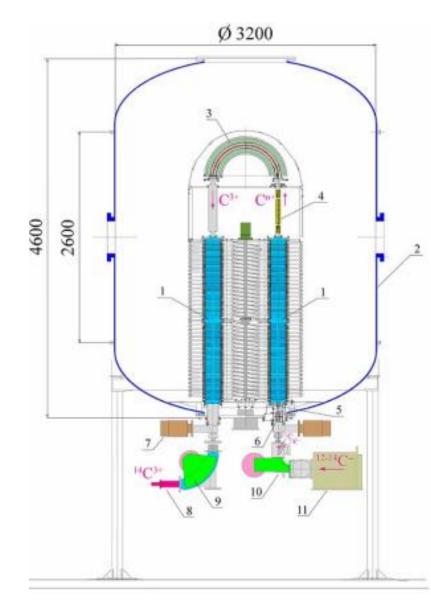


Fig. 1. Remaining energy after passage of 1 MeV ions through a 50 nm silicon nitride and a 500 nm mylar window. TRIM calculation [2].

Figure of silicon nitride membrane windows

M. Dobeli et al., Nucl. Instr. and Meth. B, 219-220 (2004) 415-419 doi:10.1016/j.nimb.2004.01.093

BINP AMS



BINP AMS characteristics:

- magnesium vapor target for molecular destruction localized site of molecular breakdown;
- sorting of ions by energy immediately after the destruction of molecular ions; effective screening of fragments of molecules; the energy of the pieces of the molecule is always less than the energy of the molecule;
- time-of-flight detector for registering the moment of ions arrival.

BINP AMS scheme:

1 – accelerator tube, 2 – accelerator body, 3 – electrostatic turn on 180°, 4 – magnesium vapor target, 5 – corrector, 6 – electrostatic lens, 7 – vacuum pump, 8 – ion detector, 9 – high energy dipole magnetic spectrometer, 10 – low energy dipole magnetic spectrometer, 11 – ion source.